

## AMENDMENT

### In the Claims:

Please amend claims 59-60 and 68-89 and add new claims 70-71 as follows.

Claims 1-23. See issued patent.

24–27. (Cancelled).

28. A method, comprising:

generating a first current that changes with temperature according to a first polarity;

generating a second current that changes with temperature according to a second polarity;

combining the first and second currents to generate a reference current; and  
comparing the reference current to a third current that is dependent on a power-supply voltage.

29. The method of claim 28 wherein:

the first current changes with temperature according to a positive polarity; and  
the second current changes with temperature according to a negative polarity.

30. The method of claim 28 wherein:

the first current is proportional to temperature; and  
the second current is inversely proportional to temperature

31. The method of claim 28 wherein:

the first current increases as temperature increases and decreases as  
temperature decreases; and

the second current decreases as temperature increases and increases as  
temperature decreases.

32. The method of claim 28 wherein combining the first and second currents comprises summing the first and second currents.

33. The method of claim 28 wherein combining the first and second currents comprises sinking the first and second currents from a node.

34. The method of claim 28 wherein combining the first and second currents comprises sourcing the first and second currents to a node.

35–39. (Cancelled)

40. A method, comprising:  
generating a first current that increases as temperature increases and that decreases as temperature decreases;  
generating a second current that decreases as temperature increases and that increases as temperature decreases;  
generating a third current that is dependent on a first voltage; and  
combining the first, second, and third currents at a node to generate a second voltage on the node.

41. The method of claim 40 wherein combining the currents comprises:  
sinking the first and second currents from the node; and  
sourcing the third current to the node.

42. The method of claim 40 wherein:  
the first current is related to a thermal voltage; and  
the second current is related to a voltage across a forward-biased p-n junction.

43. The method of claim 40 wherein:  
the first current is related to a thermal voltage; and  
the second current is related to a base-emitter voltage of a bipolar transistor.

44. The method of claim 40 wherein the second current is related to the natural logarithm of a current through a bipolar transistor.

45. A method, comprising:  
generating a first current that is related to temperature according to a first polarity;  
generating a second current that is related to temperature according to a second polarity;  
combining the first and second currents into a reference current;  
generating a third current that is dependent on a first voltage; and  
comparing the third current to the reference current.

46. The method of claim 45 wherein:  
the first current is related to a thermal voltage;  
the second current is related to a voltage across a forward-biased p-n junction;  
and  
the third current is dependent on a power-supply voltage.

47. The method of claim 45 wherein:  
combining the first and second currents comprises sinking the first and second currents from a node; and  
comparing the third current to the reference current comprises,  
sourcing the third current to the node, and  
comparing a second voltage on the node to a reference voltage.

48. A method, comprising:  
generating a first current that is proportional to a threshold voltage of a field-effect transistor;  
generating a second current that is proportional to a difference between a supply voltage and a threshold voltage of a second field-effect transistor;  
generating a third current that is proportional to a base-emitter voltage of a first bipolar transistor;

generating a fourth current that is proportional to absolute temperature; and  
driving a node with the first, second, third, and fourth currents.

49. The method of claim 48 wherein driving the node comprises:  
sourcing the first and second currents to the node; and  
sinking the third and fourth currents from the node.

50. The method of claim 48, further comprising comparing a voltage on the  
node with a reference voltage.

51. The method of claim 48 wherein the first field-effect transistor is matched  
to the second field-effect transistor.

52. The method of claim 48 wherein the threshold voltage of the first  
field-effect transistor is equal or approximately equal to the threshold voltage of the  
second field-effect transistor.

53. A method, comprising:  
generating a first current that equals a product of a first constant and a threshold  
voltage of a first field-effect transistor;  
generating a second current that equals a product of a second constant and a  
difference between a supply voltage and a threshold voltage of a second field-effect  
transistor;  
generating a third current that equals a product of a third constant and a  
base-emitter voltage of a bipolar transistor;  
generating a fourth current that equals a product of a fourth constant and a  
thermal voltage; and  
driving a node with the first, second, third, and fourth currents.

54. The method of claim 53 wherein the first constant equals the second  
constant.

55. The method of claim 53 wherein driving the node comprises:  
sourcing the first and second currents to the node; and  
sinking the third and fourth currents from the node.

56. A method, comprising:  
generating a first current that changes with temperature according to a first  
polarity;  
generating a second current that changes with temperature according to a  
second polarity;  
combining the first and second currents to generate a reference current; and  
comparing the reference current to a third current that is proportional to a  
power-supply voltage.

57. The method of claim 28 wherein comparing the reference current  
comprises summing the reference current and the third current at a node.

58. The method of claim 28 wherein comparing the reference current  
comprises:  
sinking the reference current from a node; and  
sourcing the third current to the node.

59. A method, comprising:  
generating with a first current source that is powered by a supply voltage a  
reference current that has a temperature coefficient and that is independent of the  
supply voltage;  
providing the reference current at a node;  
generating with a second current source that is powered by the supply voltage a  
supply-related current having approximately the temperature coefficient and being  
related to the supply voltage;  
providing the supply-related current at the node; and  
comparing the reference current to the supply-related current at the node.

60. The method of claim 59 wherein:  
providing the reference current at the node comprises sinking the reference  
current from the node; and  
providing the supply-related current at the node comprises sourcing the  
supply-related current to the node.

61. The method of claim 59 wherein comparing the reference current  
comprises summing the reference current and the supply-related current at the node to  
generate a voltage.

62. A method, comprising:  
generating a reference current having a first temperature coefficient;  
comparing the reference current to a supply-related current that is related to a  
power-supply voltage and that has or has approximately the first temperature  
coefficient;  
wherein comparing the reference current comprises summing the reference  
current and the supply-related current at a node to generate a voltage;  
connecting the power-supply voltage to a load if the voltage is greater than a  
predetermined level; and  
connecting a secondary supply to the load if the voltage is less than the  
predetermined level.

63. A method, comprising:  
generating a first current that is related to temperature according to a first  
polarity;  
generating a second current that is related to temperature according to a second  
polarity;  
combining the first and second currents into a reference current;  
generating a third current that is related to temperature according to the first  
polarity;  
generating a fourth current that is related to a supply voltage and that is related  
to temperature according to the second polarity;

combining the third and fourth currents into a supply-related current; and  
comparing the reference current to the supply-related current.

64. The method of claim 63 wherein the fourth current is proportional to the supply voltage.

65. The method of claim 63 wherein the supply-related current is proportional to the supply voltage.

66. The method of claim 63 wherein:  
the first and third currents are inversely proportional to temperature; and  
the second and fourth currents are proportional to temperature.

67. The direct current sum bandgap voltage comparator of claim 24 wherein  
 $K_4 = K_1$ .

68. A method, comprising:  
generating with a first current source that is powered by a supply voltage a  
reference current that has a temperature coefficient and that is independent of the  
supply voltage;  
providing the reference current at a node;  
generating with a second current source that is powered by the supply voltage a  
supply-related current having approximately the temperature coefficient and being  
related to the supply voltage;  
providing the supply-related current at the node; and  
neither sourcing to nor sinking from the node a current other than the reference  
and supply-related currents.

69. A method comprising:  
generating with a first current source that is powered by a supply voltage a  
reference current that has a temperature coefficient and that is independent of the  
supply voltage;

providing the reference current at a comparison node;  
generating with a second current source that is powered by the supply voltage a  
supply-related current having approximately the temperature coefficient and being  
related to the supply voltage;  
providing the supply-related current at the comparison node; and  
comparing a voltage on the comparison node to a reference voltage.

70. The method of claim 68 wherein:  
providing the reference current at the node comprises sinking the reference  
current from the node; and  
providing the supply-related current at the node comprises sourcing the  
supply-related current to the node.

71. The method of claim 69 wherein:  
providing the reference current at the comparison node comprises sinking the  
reference current from the comparison node; and  
providing the supply-related current at the comparison node comprises sourcing  
the supply-related current to the comparison node.